Unitized Semiconductor Devices - Page 1 of 1



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	osure Material:
Meta	-
	rall Length:
	0 inches
	ninal Length:
	0 inches
•••	rall Diameter:
	0 inches
Con	nponent Name And Quantity:
	insistor
	Inting Method:
	ninal
Terr	ninal Circle Diameter:
0.10	0 inches
Feat	tures Provided:
Herr	netically sealed case
Sem	niconductor Material:
Silic	on all transistor
Volt	age Rating In Volts Per Characteristic:
1.0	gate to source voltage all transistor
Curi	rent Rating Per Characteristic:
75.0	0 milliamperes zero-gate-voltage source current megawatts all transisto
Spe	cial Features:
All tr	ransistor junction pattern arrangement: npn
Terr	ninal Type And Quantity:
6 un	insulated wire lead
She	If Life:
N/a	
Unit	Of Measure:
Dem	nilitarization:
No	
Fiig	:
A11	0a0